Customer No.: 31561

Docket No.: 13041-US-PA

Application No.: 10/710,732

REMARKS

Present Status of the Application

It is noted with great appreciation that the Office has allowed claims 16-20. However, the

Office has rejected claims 1-15 under 35 U.S.C. 103(a) as being unpatentable over Rhodes (US

6,569,700) in view of Shibib (US 6,228,750). The Office has also rejected the claims 10-11, 13

under 35 U.S.C 112, 2<sup>nd</sup> paragraph, for providing insufficient antecedent basis.

Claims 1-20 remain pending in the present application of which claims 1, 10-11 and 13

have been amended to more accurately describe the present invention. It is believed that no

new matter is added by way of these amendments made to the claims or otherwise to the

application.

Applicant has most respectfully considered the remarks set forth in this Office Action.

Regarding the obvious rejections, it is however strongly believed that the cited references are

deficient to adequately teach the claimed features as recited in the presently pending claims. The

reasons that motivate the above position of the Applicant are discussed in detail hereafter, upon

which reconsideration of the claims is most earnestly solicited.

Discussion of Office Action Objections and Rejections

The Office Action rejected the specification and claims 10, 11 and 13 under 35 U.S.C.

§112, 2<sup>nd</sup> paragraph as failing to provide sufficient antecedent basis for the limitation

"forming, a material constituting and an annealing operation" in a buffer layer in the claim. .

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In response thereto, Applicants have amended claims 10-11 and 13 to properly depend on

claim 9. Applicants believe that the amendments made to the claims have rectified the 112, 2<sup>nd</sup>

paragraph rejections. Reconsideration and withdrawal of the rejection are courteously requested.

The Office Action rejected claims 1-15 under 35 U.S.C. 103(a) as being unpatenable over

the Rhodes (USP 6,611,037) in view of Shibib (USP 6,228,750).

With regard to the 103 rejections of the claims by Rhodes in view of Shibib, Applicants

respectfully traverse the rejection for at least the reasons that Rhodes and Shibib, neither alone

nor in combination, teach or suggest each and every element of the claims in issue.

Regarding the prior art reference Rhodes, Rhodes discloses forming a plurality of trenches

in a well region of a substrate. As conceded by the Office, the doped layer 311 in the trench of

Rhodes is formed by doping the well region (col. 8, lines 45-55), which fundamentally teaches

away the feature of "depositing a doped layer of a second conductive type over the well region of

the first conductive type in the substrate".

The Office then relies on Shibib and asserts that Shibib teaches the missing feature.

Applicants respectfully disagree. The coating material 107 of Shibib, which is construed to be

comparable to the doped layer of a second conductive type of the invention, is a sacrificial layer,

which is formed and is eventually removed or altered to be non-conductive. As specifically

taught in col. 4, lines 15-19 of Shibib, "the in-situ doped polysilicon may be allowed to oxidize

to form a dielectric isolation layer or be removed through etching techniques". The present

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invention teaches, on the other hand, that the doped layer of a second conductive type of the

invention must be retained in order to form the photodiode of the invention. The removal of the

doped layer will render the claimed invention inoperable. Hence, the motivation to combine

Rhodes with Shibib to obtain the claimed invention is lacking.

For at least the reasons that discussed above, Applicants submit that the combination of

Rhodes and Shibib still fails to render claim 1-15 unpatentable. Withdrawal of the rejection is

respectfully requested.

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Respectfully submitted,

Registration No.: 46,863

## **CONCLUSION**

For at least the foregoing reasons, it is believed that the pending claims are in proper condition for allowance. If the Examiner believes that a telephone conference would expedite the examination of the above-identified patent application, the Examiner is invited to call the undersigned.

Date:

May 9, 2011

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